

XL526

Features

- Wide Operating Voltage Range: 3.3V~45V
- Low Quiescent Current : 2.0mA
- Device HBM ESD Classification Level Class3B
- Reverse Supply Protection
- Excellent Magnetic Field Symmetry
- 40mA Load Capacity
- SOT23-3 package
- Magnetic Field Operate Point: 100Gs
- Magnetic Field Release Point: -100Gs

Applications

- Power Tools
- Flow Meters
- Valve and Solenoid Status
- Brushless DC Motors
- Tachometers

General Description

The XL526 is a latching Hall switch sensor that optimized for wide voltage, low quiescent current and wide temperature range. XL526 supports a power supply voltage of up to 50V and provide a load capacity of up to 40mA. Widely used in automotive electronics, industrial control and other applications. Adopting a collector open circuit output architecture, it has strong resistance to electromagnetic interference.

The XL526 integrates a reference voltage source, temperature compensation, Hall array, differential comparator, hysteresis latch, and power output stage, providing high magnetic field response sensitivity, symmetry, and strong immunity to electromagnetic interference over the full voltage range and full temperature range.

Typical application schematic

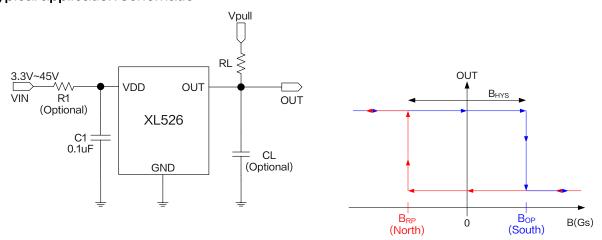


Figure 1. XL526 Typical application schematic and output characteristic curve



Pin Configurations

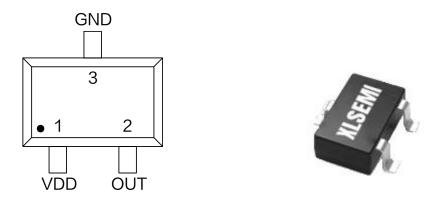


Figure 2. Pin Configuration of XL526

Table 1 Pin Description

Pin Number	Pin Name	Description
1	VDD	Supply Voltage Input Pin. XL526 operates from 3.3V to 45V DC voltage.
2	OUT	Open Collector Output Pin, requires a resistor pull-up.
3	GND	Ground pin.

Ordering Information

Order Information	Marking ID	Package Type	Eco Plan	Packing Type Supplied As
XL526	XL526	SOT23-3	RoHS & HF	3000 Units Per Reel



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Function Block

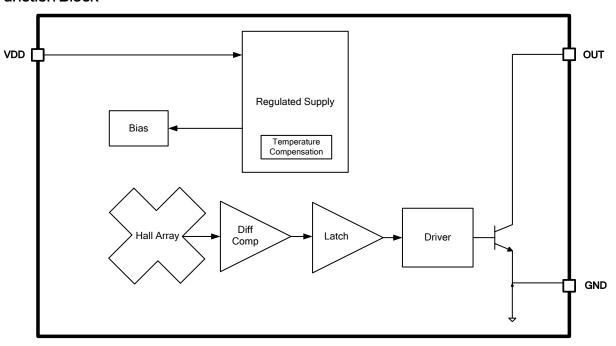


Figure 3. Function Block Diagram of XL526

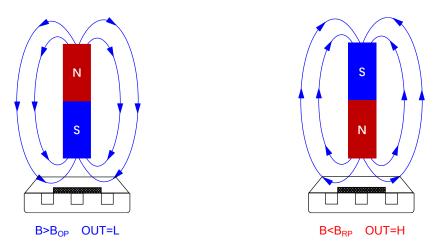


Figure 4. Magnetic Field Direction Definition



Absolute Maximum Ratings (Note1)

Parameter	Symbol	Value	Unit
Input Voltage	V_{DD}	-50 ~ 50	V
Output Pin Voltage	V _{out}	−0.5 ~ 50	V
Output Pin Current Sink	Isink	0~40	mA
Thermal Resistance (SOT23-3) (Junction to Ambient, No Heatsink, Free Air)	RJA	200	°C/W
Operating Temperature	T _A	−40 ~ 125	${\mathbb C}$
Operating Junction Temperature	TJ	−40 ~ 150	${\mathbb C}$
Storage Temperature	T _{STG}	−65 ~ 150	$^{\circ}$
Lead Temperature (Soldering, 10 sec)	T _{LEAD}	260	${\mathbb C}$
ESD (HBM)		>8000	V

Note1: Stresses greater than those listed under Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.



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XL526 Electrical Characteristics

 T_A = 25°C, V_{DD} =Vpull=5V, RL=1k Ω , R1=0 Ω ; system parameters test circuit figure1, unless otherwise specified.

Parameters	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Operation Voltage	$V_{ extsf{DD}}$		3.3		45	V
Reverse Supply Voltage	$V_{ extsf{DDR}}$		-45			V
Operation Supply Current	I _{DD_H}	OUT=H		2.0		mA
Operation Supply Current	I _{DD_L}	OUT=L		2.5		mA
Power-on time	ton			35	50	uS
Output Saturation Voltage	Vsat	I _{оит} =30mA		0.2	0.3	V
Output Delay Time	t _d	B=B _{RP} to B _{OP}		10	25	uS
Output Rise Time	t _r	CL=50pF			0.5	uS
Output Fall Time	t _f	CL=50pF			0.2	uS

XL526 Magnetic Characteristics (Note2)

 $T_A = 25^{\circ}C$, $V_{DD} = V_{DD} = V_{DD} = 1k\Omega$, R1=0 Ω ; system parameters test circuit figure1, unless otherwise specified.

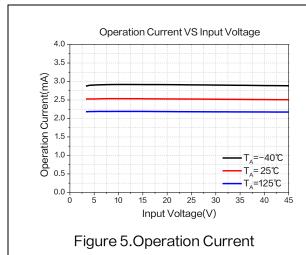
Parameters	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Bandwidth	f _{BW}				100	KHz
Magnetic Field Operate Point	Вор		+60	+100	+140	Gs
Magnetic Field Release Point	B _{RP}		-140	-100	-60	Gs
Magnetic Hysteresis	B _{HYS}			200		Gs
Magnetic Offset	Во	Bo=(Bop+BRP)/2	-40	0	+40	Gs

Note2: A south pole near the marked side of the package is a positive magnetic field; Powering-on the device in the hysteresis region allows an indeterminate output state. The correct state is attained after the first excursion beyond B_{OP} or B_{RP} .



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Typical Characteristics



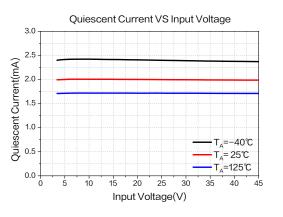


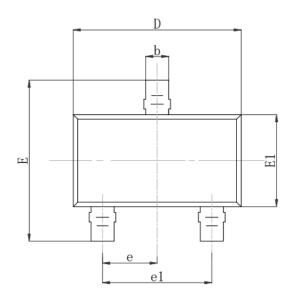
Figure 6. Quiescent Current

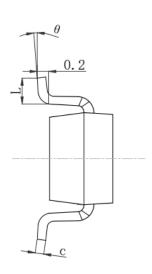


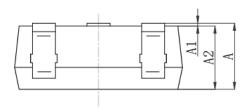
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Package Information

SOT23-3







Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	1.05	1.25	0.041	0.049	
A1	0.00	0.10	0.000	0.004	
A2	1.05	1.15	0.041	0.045	
b	0.30	0.50	0.012	0.020	
С	0.10	0.20	0.004	0.008	
D	2.82	3.05	0.111	0.120	
E1	1.50	1.70	0.059	0.067	
E	2.65	2.95	0.104	0.116	
е	0.95	REF.	0.037	REF.	
e1	1.80	2.00	0.071	0.079	
L	0.30	0.60	0.012	0.024	
θ	0°	8°	0°	8°	



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